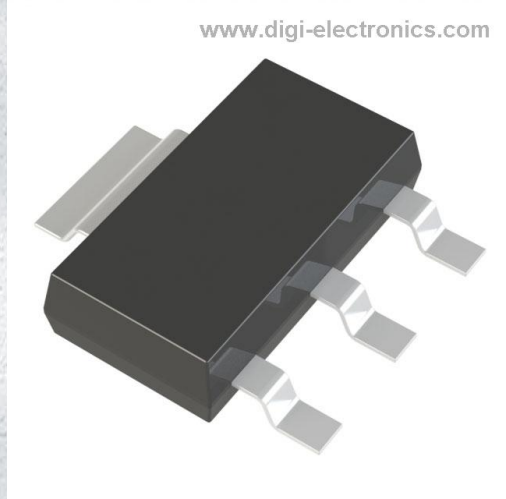
ZX5T851GTA Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number	ZX5T851GTA-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	ZX5T851GTA
Description	TRANS NPN 60V 6A SOT223-3
Detailed Description	Bipolar (BJT) Transistor NPN 60 V 6 A 130MHz 3 W Surface Mount SOT-223-3

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
ZX5T851GTA	Diodes Incorporated
Series:	Product Status:
-	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	6 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ Ib, Ic:
60 V	260mV @ 300mA, 6A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
20nA (ICBO)	100 @ 2A, 1V
Power - Max:	Frequency - Transition:
3 W	130MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-261-4, TO-261AA	SOT-223-3
Base Product Number:	
ZX5T851	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.29.0075	

A Product Line of
Diodes Incorporated

ZX5T851G

60V NPN MEDIUM POWER LOW SATURATION TRANSISTOR IN SOT223

Features

- BV_{CEO} > 60V
- I_C = 6A High Continuous Collector Current
- I_{CM} = 20A Peak Pulse Current
- Low Saturation Voltage $V_{CE(sat)}$ < -60mV @ -1A
- R_{SAT} = 35mΩ for a Low Equivalent On-Resistance
- h_{FE} Specified up to 10A for a High Gain Hold-Up
- Complementary PNP Type: ZX5T951G
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

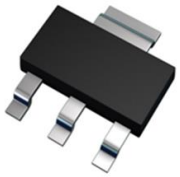
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.112 grams (Approximate)

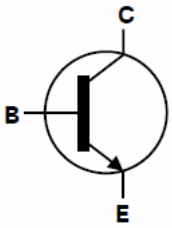
Applications

- Emergency Lighting Circuits
- MOSFET & IGBT Gate Drivers
- Solenoid, Relay and Actuator Drivers
- DC Modules
- Motor Control

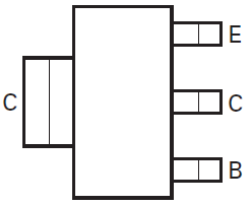
SOT223



Top View



Device Symbol



Top View
Pin-Out

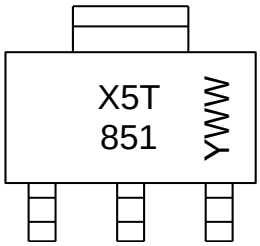
Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZX5T851GTA	AEC-Q101	X5T851	7	12	1,000
ZX5T851GTC	AEC-Q101	X5T851	13	12	4,000

Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at http:// www.diodes.com/products/packages.html.

Marking Information

SOT223



X5T 851 = Product Type Marking Code
YWW = Date Code Marking
Y or $\overline{Y}$ = Last Digit of Year (ex: 5= 2015)
WW or $\overline{W}W$ = Week Code (01~53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	150	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	I_C	6	A
Peak Pulse Current	I_{CM}	20	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

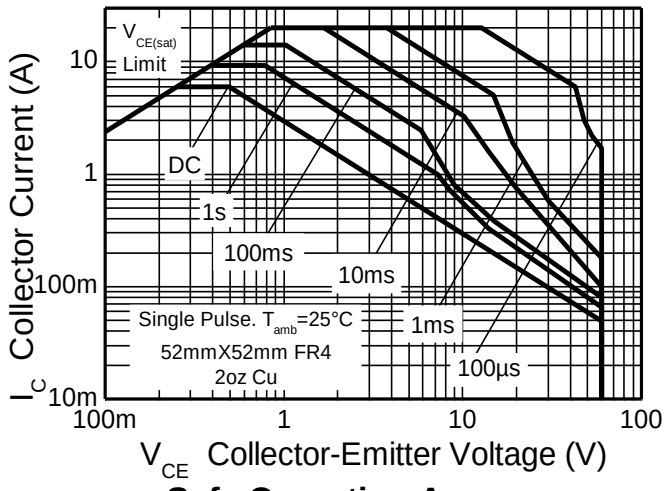
Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_D	3.0	W
	(Note 6)		2.0	
	(Note 7)		1.6	
	(Note 8)		1.2	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	41.7	°C/W
	(Note 6)		62.5	
	(Note 7)		78.1	
	(Note 8)		104	
Thermal Resistance Junction to Lead	(Note 9)	$R_{\theta JL}$	10.5	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 8)

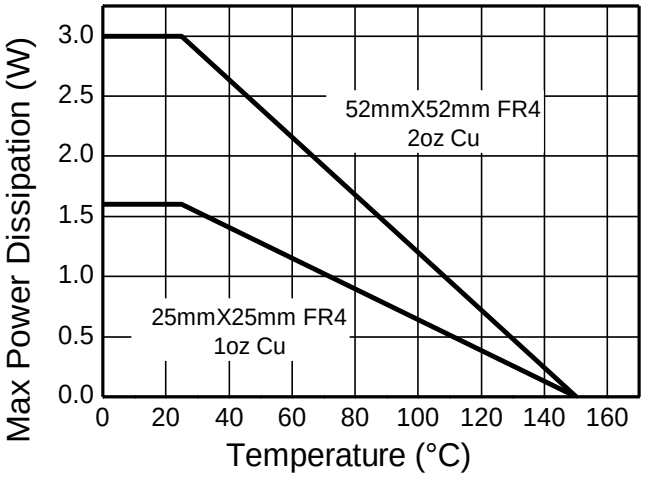
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:
5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
8. Same as Note 5, except the device is mounted on minimum recommended pad layout.
9. Thermal resistance from junction to solder-point (at the end of the collector lead).
10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

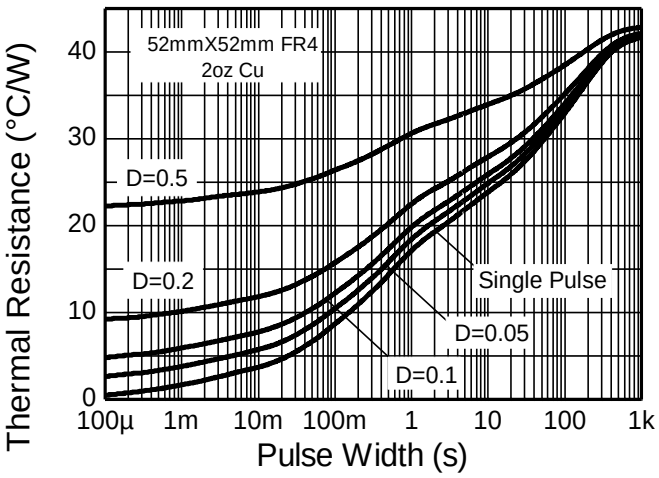
Thermal Characteristics and Derating Information



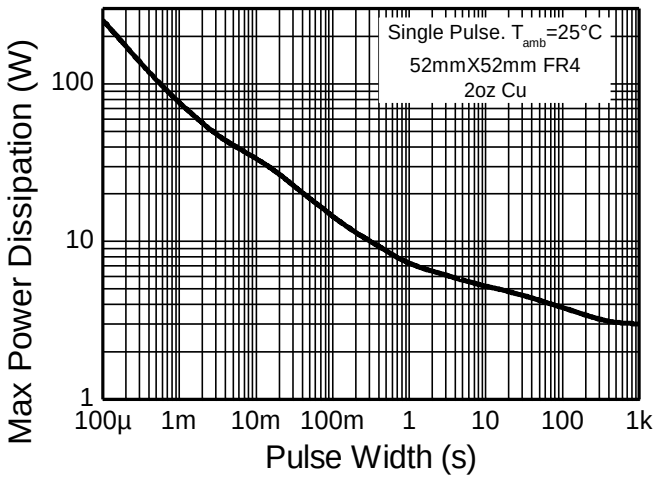
Safe Operating Area



Derating Curve



Transient Thermal Impedance



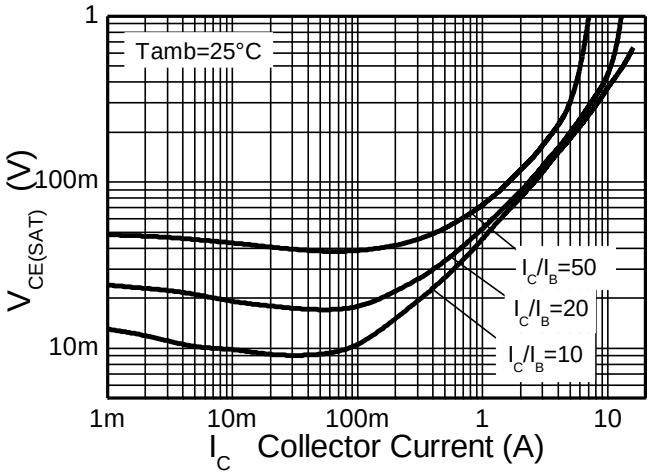
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

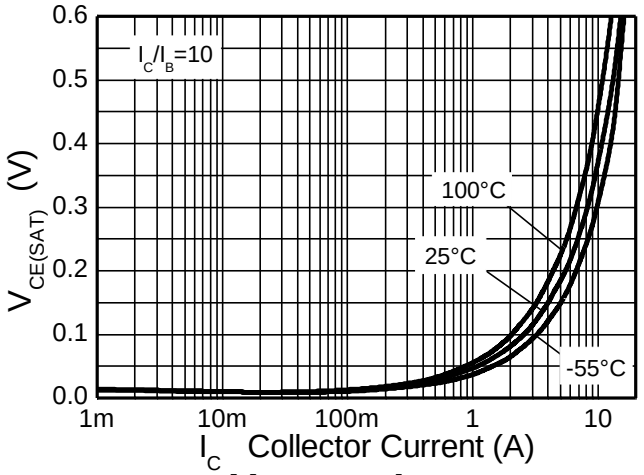
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	150	190	–	V	I_C = 100µA
Collector-Emitter Breakdown Voltage	BV_{CER}	150	190	–	V	I_C = -1µA, R_B ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 11)	BV_{CEO}	60	80	–	V	I_C = 10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	7	8.1	–	V	I_E = 100µA
Collector Cut-Off Current	I_{CBO}	– –	<1 –	20 0.5	nA µA	V_{CB} = 120V V_{CB} = 120V, T_A = +100°C
Collector Cut-Off Current	I_{CER} R_B ≤ 1kΩ	– –	<1 –	20 0.5	nA µA	V_{CB} = 120V V_{CB} = 120V, T_A = +100°C
Emitter Cut-Off Current	I_{EBO}	–	<1	10	nA	V_{EB} = 6V
Collector-Emitter Saturation Voltage (Note 11)	$V_{CE(sat)}$	–	20	30	mV	I_C = 100mA, I_B = 5mA
		–	45	60		I_C = 1A, I_B = 100mA
		–	50	70		I_C = 1A, I_B = 50mA
		–	100	135		I_C = 2A, I_B = 50mA
		–	210	260		I_C = 6A, I_B = 300mA
Base-Emitter Saturation Voltage (Note 11)	$V_{BE(sat)}$	–	1000	1100	mV	I_C = 6A, I_B = 300mA
Base-Emitter Turn-On Voltage (Note 11)	$V_{BE(on)}$	–	940	1050	mV	I_C = 6A, V_{CE} = 1V
DC Current Gain (Note 11)	h_{FE}	100	200	–	–	I_C = 10mA, V_{CE} = 1V
		100	200	300		I_C = 2A, V_{CE} = 1V
		55	105	–		I_C = 5A, V_{CE} = 1V
		20	40	–		I_C = 10A, V_{CE} = 1V
Output Capacitance	C_{obo}	-	31	-	pF	V_{CB} = 10V. f = 1MHz
Current Gain-Bandwidth Product	f_T	-	130	–	MHz	V_{CE} = 5V, I_C = 100mA, f = 100MHz
Switching Times	t_{on}	–	42	–	ns	I_C = 1A, V_{CC} = 10V, I_{B1} = -I_{B2} = 100mA
	t_{off}	–	760	-		

Note: 11. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

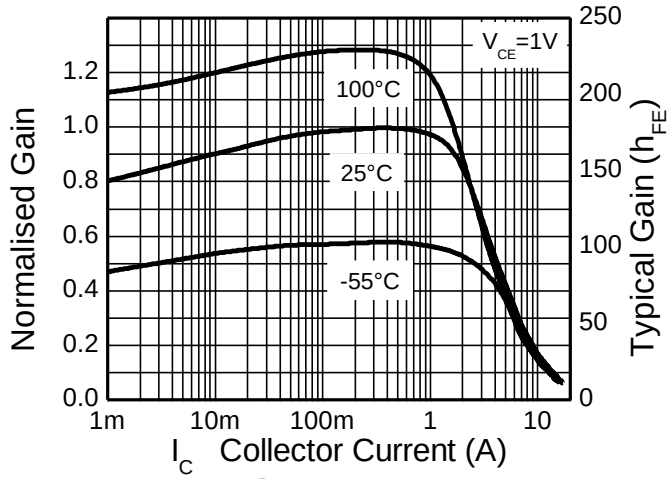
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



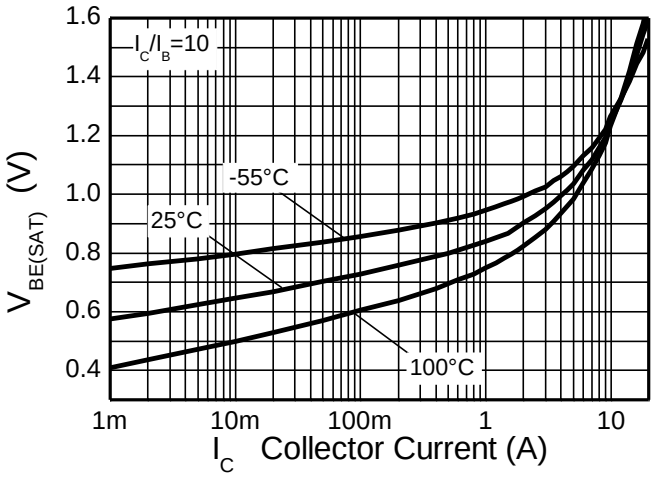
$V_{CE(SAT)}$ v I_C



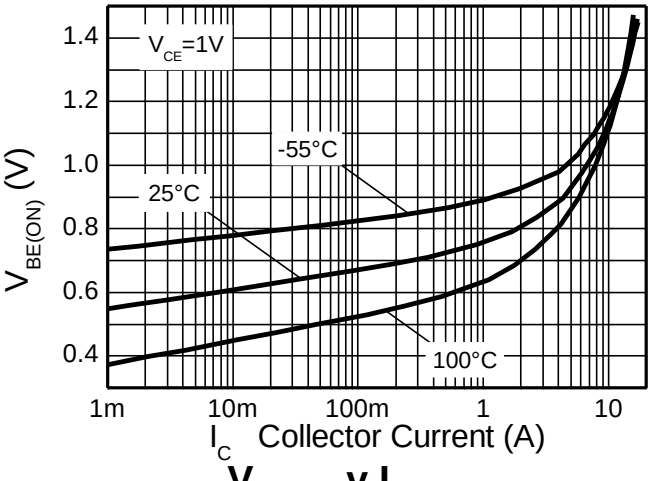
$V_{CE(SAT)}$ v I_C



h_{FE} v I_C



$V_{BE(SAT)}$ v I_C



$V_{BE(ON)}$ v I_C

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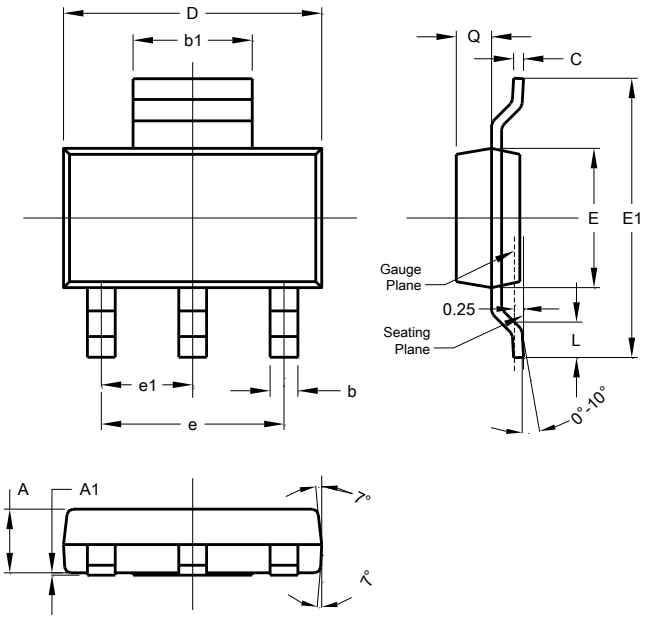
Package Outline Dimensions

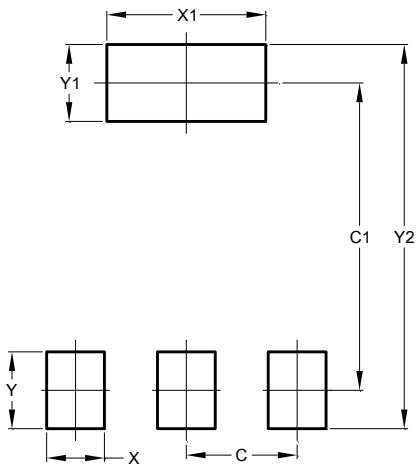
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223			
Dim	**Min**	**Max**	**Typ**
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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ZX5T851G

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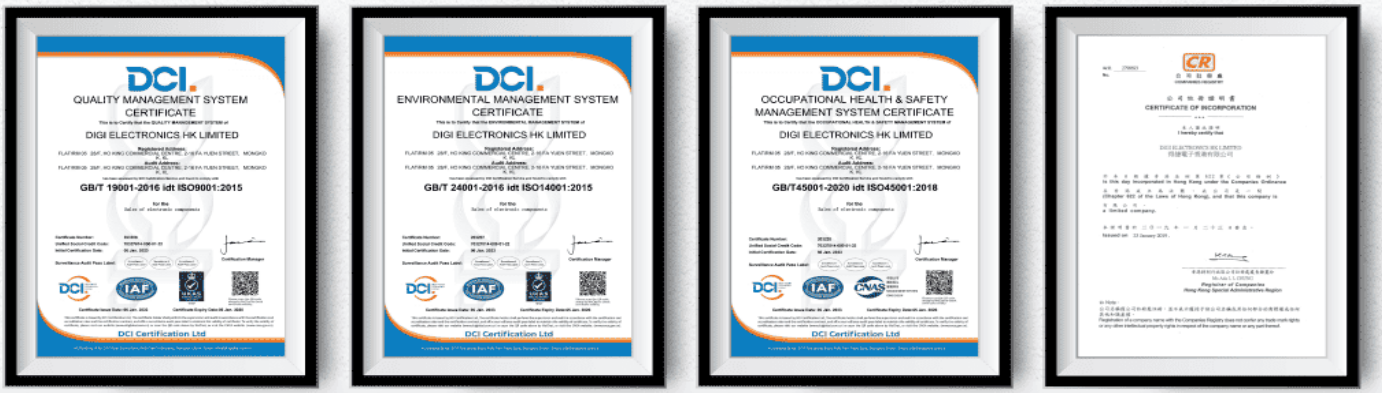

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